

## N-Channel Enhancement Mode MOSFET

### 1. Product Information

#### 1.1 Features

- ☒ Surface Mounted Package
- ☒ Super Trench
- ☒  $T_J \text{ max } 175^\circ\text{C}$
- ☒ Low Thermal Resistance
- ☒ MSL1

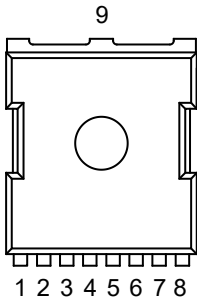
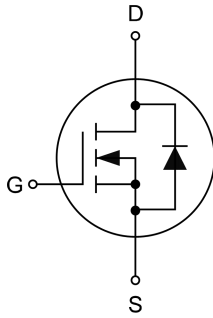
#### 1.2 Applications

- ☒ Motor drivers
- ☒ DC/DC Converter

#### 1.3 Quick reference

- ☒  $BV \geq 30 \text{ V}$
- ☒  $P_{\text{tot}} \leq 115 \text{ W}$
- ☒  $I_D \leq 256 \text{ A}$
- ☒  $R_{\text{DS(ON)}} \leq 0.9 \text{ m}\Omega @ V_{\text{GS}} = 10 \text{ V}$
- ☒  $R_{\text{DS(ON)}} \leq 1.4 \text{ m}\Omega @ V_{\text{GS}} = 4.5 \text{ V}$

### 2. Pin Description

| Pin           | Description | Simplified Outline                                                                                               | Symbol                                                                                |
|---------------|-------------|------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|
| 1             | Gate        |  <p>Top View<br/>TOLL-8L</p> |  |
| 2,3,4,5,6,7,8 | Source      |                                                                                                                  |                                                                                       |
| 9             | Drain       |                                                                                                                  |                                                                                       |

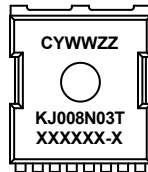
## 3. Limiting Values

| Symbol          | Parameter                                        | Conditions                                    | Min | Max      | Unit                 |
|-----------------|--------------------------------------------------|-----------------------------------------------|-----|----------|----------------------|
| $V_{DS}$        | Drain-Source Voltage                             | $T_C=25^{\circ}\text{C}$                      | 30  | -        | V                    |
| $V_{GS}$        | Gate-Source Voltage                              | $T_C=25^{\circ}\text{C}$                      | -   | $\pm 20$ | V                    |
| $I_D$           | Drain Current                                    | $T_C=25^{\circ}\text{C}, V_{GS}=10\text{ V}$  | -   | 256      | A                    |
|                 |                                                  | $T_C=100^{\circ}\text{C}, V_{GS}=10\text{ V}$ | -   | 181      | A                    |
| $I_{DM}^{**}$   | Pulsed Source Current                            | $T_C=25^{\circ}\text{C}, V_{GS}=10\text{ V}$  | -   | 1024     | A                    |
| $P_{tot}^{*}$   | Total Power Dissipation                          | $T_C=25^{\circ}\text{C}$                      | -   | 115      | W                    |
| $I_S$           | Diode Forward Current                            | $T_C=25^{\circ}\text{C}$                      | -   | 87       | A                    |
| $E_{AS}$        | Single Pulsed Avalanche Energy                   | $V_{DD}=20\text{ V}, L=0.3\text{ mH}$         | -   | 1125     | mJ                   |
| $T_J, T_{stg}$  | Operating Junction and Storage Temperature Range |                                               | -55 | 175      | $^{\circ}\text{C}$   |
| $R_{\theta JA}$ | Thermal Resistance-Junction to Ambient           |                                               | -   | 50       | $^{\circ}\text{C/W}$ |
| $R_{\theta JC}$ | Thermal Resistance-Junction to Case              |                                               | -   | 1.3      |                      |

Notes:

- \* Surface mounted on 1 in<sup>2</sup> pad area,  $t \leq 10\text{ sec.}$
- \*\* Pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .
- \*\*\* Limited by bonding wire.

## 4. Marking Information

| Product Name | Marking                                                                               |
|--------------|---------------------------------------------------------------------------------------|
| KJ008N03T    |  |

## 5. Ordering Code

| Product Name | Package | Reel size | Tape width | Quantity (pcs) |
|--------------|---------|-----------|------------|----------------|
| KJ008N03T    | TOLL-8L | 13"       | 24 mm      | 2000           |

Note: KUAJIEXIN defines "Green" as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC/JEDEC J-STD-020C).

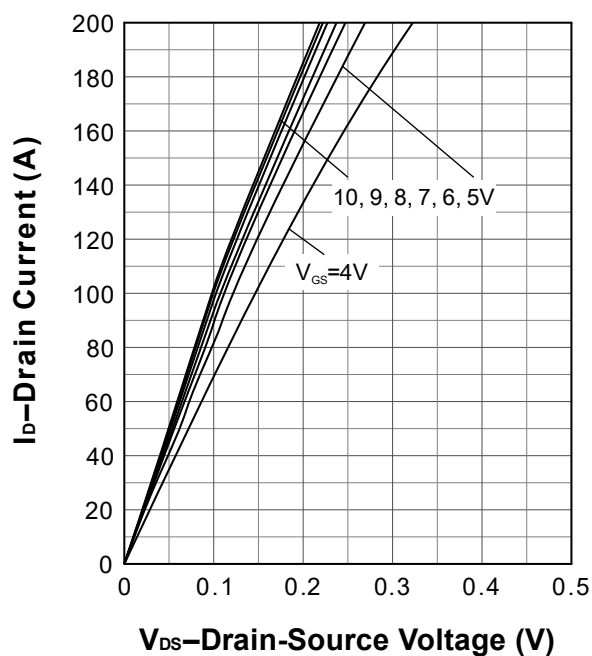
## 6. Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

| Symbol                      | Parameter                        | Conditions                                                                              | Min | Typ  | Max  | Unit |
|-----------------------------|----------------------------------|-----------------------------------------------------------------------------------------|-----|------|------|------|
| Static Characteristics      |                                  |                                                                                         |     |      |      |      |
| BV <sub>DSS</sub>           | Drain-Source Breakdown Voltage   | V <sub>GS</sub> =0 V, I <sub>DS</sub> =250 μA                                           | 30  | -    | -    | V    |
| V <sub>GS(th)</sub>         | Gate Threshold Voltage           | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>DS</sub> =250 μA                              | 1   | -    | 2    | V    |
| I <sub>DSS</sub>            | Zero Gate Voltage Source Current | V <sub>DS</sub> =24 V, V <sub>GS</sub> =0 V                                             | -   | -    | 1    | μA   |
| I <sub>GSS</sub>            | Gate Leakage Current             | V <sub>GS</sub> =±20 V, V <sub>DS</sub> =0 V                                            | -   | -    | ±100 | nA   |
| R <sub>DS(ON)</sub>         | Drain-Source On-State Resistance | V <sub>GS</sub> =10 V, I <sub>DS</sub> =20 A                                            | -   | 0.75 | 0.9  | mΩ   |
|                             |                                  | V <sub>GS</sub> =4.5 V, I <sub>DS</sub> =15 A                                           | -   | 1.1  | 1.4  |      |
| Diode Characteristics       |                                  |                                                                                         |     |      |      |      |
| V <sub>SD</sub>             | Diode Forward Voltage            | I <sub>SD</sub> =10 A, V <sub>GS</sub> =0 V                                             | -   | -    | 1.1  | V    |
| t <sub>rr</sub>             | Reverse Recovery Time            | I <sub>SD</sub> =10 A, dI <sub>SD</sub> /dt=100 A/μs                                    | -   | 37   | -    | ns   |
| Q <sub>rr</sub>             | Reverse Recovery Charge          |                                                                                         | -   | 36   | -    | nC   |
| Dynamic Characteristics     |                                  |                                                                                         |     |      |      |      |
| C <sub>iss</sub>            | Input Capacitance                | V <sub>GS</sub> =0 V, V <sub>DS</sub> =15 V, f=1 MHz                                    | -   | 6550 | -    | pF   |
| C <sub>oss</sub>            | Output Capacitance               |                                                                                         | -   | 995  | -    |      |
| C <sub>rss</sub>            | Reverse Transfer Capacitance     |                                                                                         | -   | 770  | -    |      |
| t <sub>d(on)</sub>          | Turn-on Delay Time               | V <sub>DS</sub> =15 V, V <sub>GEN</sub> =10 V, R <sub>G</sub> =6 Ω, I <sub>D</sub> =1 A | -   | 14   | -    | ns   |
| t <sub>r</sub>              | Turn-on Rise Time                |                                                                                         | -   | 24   | -    |      |
| t <sub>d(off)</sub>         | Turn-off Delay Time              |                                                                                         | -   | 330  | -    |      |
| t <sub>f</sub>              | Turn-off Fall Time               |                                                                                         | -   | 134  | -    |      |
| Gate Charge Characteristics |                                  |                                                                                         |     |      |      |      |
| Q <sub>g</sub>              | Total Gate Charge                | V <sub>DS</sub> =15 V, V <sub>GS</sub> =10 V, I <sub>D</sub> =20 A                      | -   | 178  | -    | nC   |
| Q <sub>gs</sub>             | Gate-Source Charge               |                                                                                         | -   | 32   | -    |      |
| Q <sub>gd</sub>             | Gate-Drain Charge                |                                                                                         | -   | 30   | -    |      |

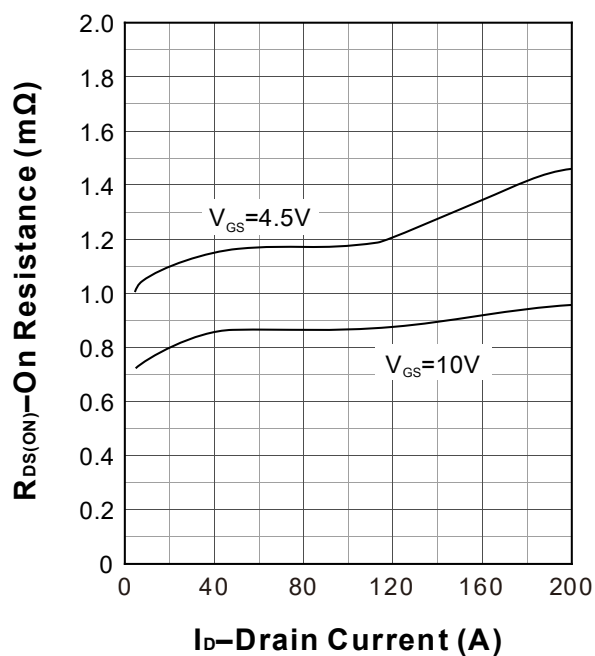
## **7. Typical Characteristics**

## 7. Typical Characteristics (cont.)

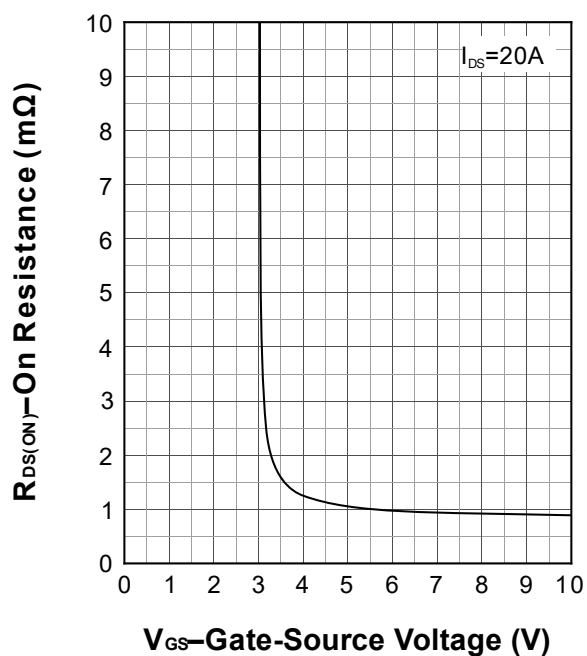
Output Characteristics



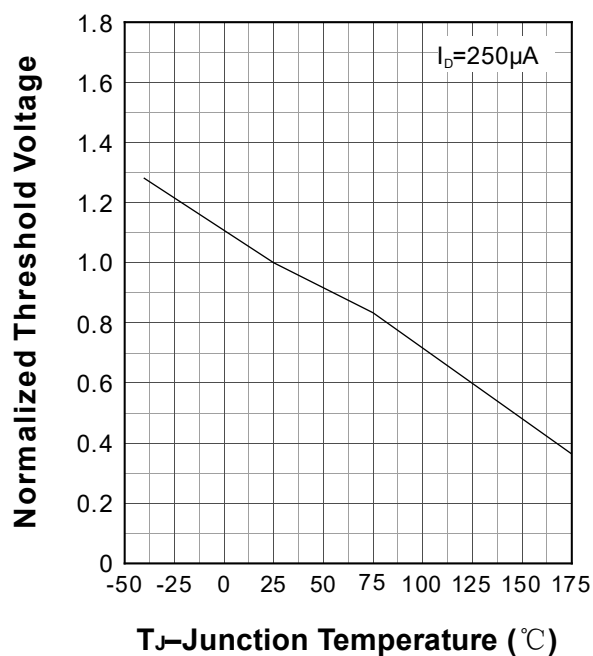
On Resistance



Transfer Characteristics

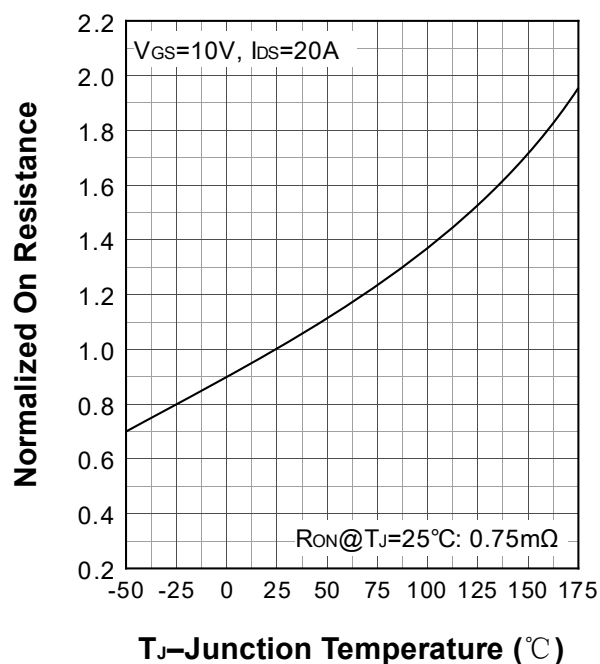


Normalized Threshold Voltage

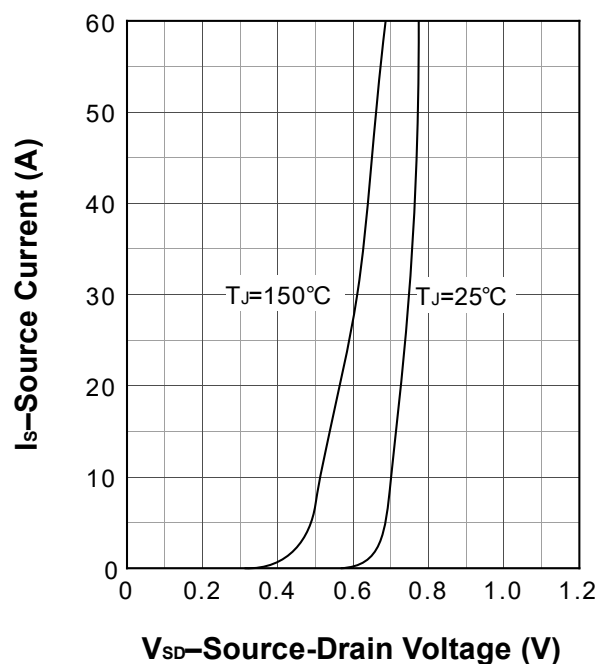


## 7. Typical Characteristics (cont.)

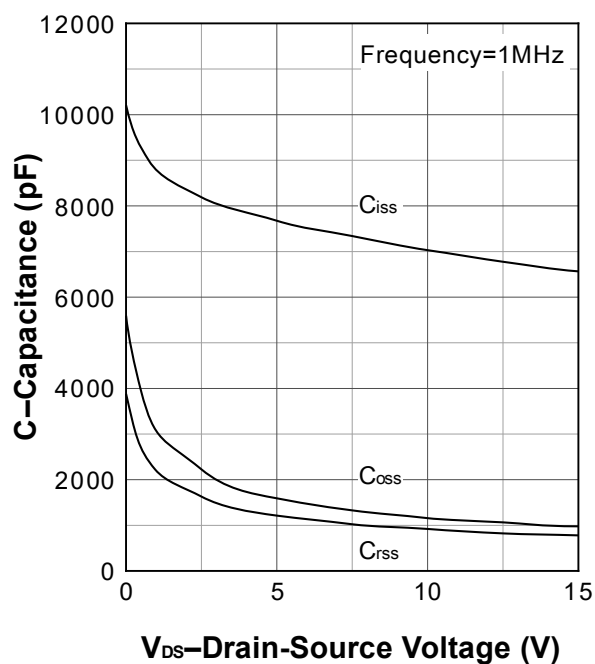
**Normalized On Resistance**



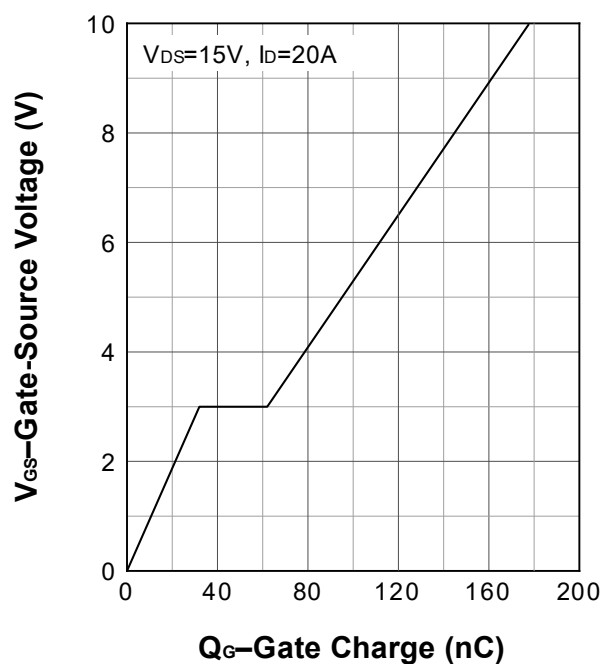
**Diode Forward Current**



**Capacitance**

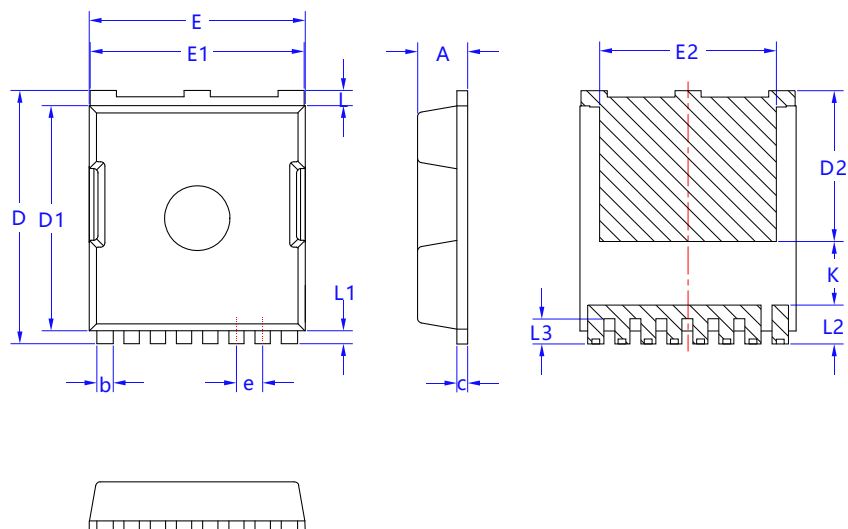


**Gate Charge**



## 8. Package Dimensions

### TOLL-8L Package



| Symbol | Dimensions in Millimeters |       |       |
|--------|---------------------------|-------|-------|
|        | MIN                       | NOM   | MAX   |
| A      | 2.20                      | 2.30  | 2.40  |
| b      | 0.60                      | 0.70  | 0.90  |
| c      | 0.40                      | 0.50  | 0.60  |
| D      | 11.48                     | 11.68 | 11.88 |
| D1     | 10.28                     | 10.38 | 10.55 |
| D2     | 6.85                      | 6.95  | 7.05  |
| E      | 9.80                      | 9.90  | 10.0  |
| E1     | 9.70                      | 9.80  | 9.90  |
| E2     | 8.00                      | 8.10  | 8.20  |
| e      | 1.20 BSC                  |       |       |
| L      | 0.60 TYPE                 |       |       |
| L1     | 0.60 TYPE                 |       |       |
| L2     | 1.60                      | 1.80  | 2.10  |
| L3     | 1.00                      | 1.15  | 1.30  |
| K      | 2.90 TYPE                 |       |       |